### **General Description**

The MAX5839 contains eight 13-bit, voltage-output digital-to-analog converters (DACs). On-chip precision output amplifiers provide the voltage outputs. The device operates from +14V/-9V supplies. Its bipolar output voltage swing ranges from +9V to -4V and is achieved with no external components. The MAX5839 has three pairs of differential reference inputs; two of these pairs are connected to two DACs each, and a third pair is connected to four DACs. The references are independently controlled, providing different full-scale output voltages to the respective DACs. The MAX5839 operates within the following voltage ranges: VDD = +7V to +14V, VSS = -5V to -9V, and VCC = +4.75V to +5.25V.

The MAX5839 features double-buffered interface logic with a 13-bit parallel data bus. Each DAC has an input latch and a DAC latch. Data in the DAC latch sets the output voltage. The eight input latches are addressed with three address lines. Data is loaded to the input latch with a single write instruction. An asynchronous load input (LD) transfers data from the input latch to the DAC latch. The LD input controls all DACs; therefore, all DACs can be updated simultaneously by asserting the LD pin.

An asynchronous  $\overline{\text{CLR}}$  input sets the output of all eight DACs to the respective DUTGND input of the op amp. Note that  $\overline{\text{CLR}}$  is a CMOS input, which is powered by V<sub>DD</sub>. All other logic inputs are TTL/CMOS compatible.

The "A" grade of the MAX5839 has a maximum INL of  $\pm 2LSBs$ , while the "B" grade has a maximum INL of  $\pm 4LSBs$ . Both grades are available in 44-pin MQFP packages.

#### **Applications**

Arbitrary Function Generators Avionics Equipment Minimum Component Count Analog Systems Digital Offset/Gain Adjustment SONET Applications Automatic Test Equipment (ATE)

Industrial Process Controls

Functional Diagram appears at end of data sheet.

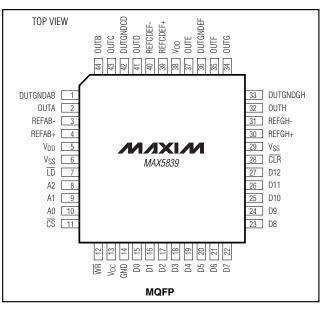
### **Features**

- Full 13-Bit Performance Without Adjustments
- 8 DACs in a Single Package
- Buffered Voltage Outputs
- ♦ Unipolar or Bipolar Voltage Swing to +9V and -4V
- ♦ 22µs Output Settling Time
- Drives up to 10,000pF Capacitive Load
- Low Output Glitch: 30mV
- Low Power Consumption: 10mA (typ)
- Small Package: 44-Pin MQFP
- Double-Buffered Digital Inputs
- Asynchronous Load Updates All DACs Simultaneously
- Asynchronous CLR Forces All DACs to DUTGND Potential

### **Ordering Information**

PART	TEMP. RANGE	PIN- PACKAGE	INL (LSB)
MAX5839ACMH	0°C to +70°C	44 MQFP	±2
MAX5839BCMH	0°C to +70°C	44 MQFP	±4
MAX5839AEMH	-40°C to +85°C	44 MQFP	±2
MAX5839BEMH	-40°C to +85°C	44 MQFP	±4

### **Pin Configuration**



### 

Maxim Integrated Products 1

For free samples & the latest literature: http://www.maxim-ic.com, or phone 1-800-998-8800. For small orders, phone 1-800-835-8769.

### **ABSOLUTE MAXIMUM RATINGS**

V <sub>DD</sub> to GND Vss to GND V <sub>CC</sub> to GND	11V to +0.3V
A_, D_, WR, CS, LD, CLR to GND REF+, REF,	
DUTGND	( 22 )
Maximum Current into REF Maximum Current into Any Signal R	

OUT\_ Short-Circuit Duration to  $V_{DD}$ ,  $V_{SS}$ , and GND ...... 1sec Continuous Power Dissipation (TA = +70°C)

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND} = 0, V_{REF} = - + = +4.500V, V_{REF} = - - = -2.000V, R_L = 10k\Omega, C_L = 50pF, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C. )$ 

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
STATIC PERFORMANCE (ANAL	OG SECTION	1)				
Resolution	N		13			Bits
Polotivo Apouropy	INL	MAX5839A			±2	LSB
Relative Accuracy	IINL	MAX5839B			±4	LSB
Differential Nonlinearity	DNL	Guaranteed monotonic			±1	LSB
Zero-Scale Error	ZSE			±2	±4	LSB
Full-Scale Error	FSE			±4	±8	LSB
Gain Error				±2	±5	LSB
Gain Temperature Coefficient		(Note 1)		0.15	20	ppm FSR/°C
DC Crosstalk		(Note 1)		14	75	μV
REFERENCE INPUTS			I			
Input Resistance			1			MΩ
Input Current				±1	±10	μA
REF+ Input Range			0.5		4.5	V
REF Input Range			-2.0		-0.5	V
(REF+) - (REF) Range			2		6.5	V
ANALOG OUTPUTS		L				
Maximum Output Voltage			9	V <sub>DD</sub> - 2		V
Minimum Output Voltage				Vss + 2	-4	V
Resistive Load to GND			5			kΩ
Capacitive Load to GND		(Note 2)			10,000	pF
DC Output Impedance		(Note 1)			0.5	Ω

**MAX5839** 

# **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND} = 0, V_{REF} = - + = +4.500V, V_{REF} = - - = -2.000V, R_L = 10k\Omega$ ,  $C_L = 50pF$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DUTGNDCHARACTERIST	rics					1
Input Impedance per DAC			40	84		kΩ
Input Current per DAC		(Note 1)	-165		100	μA
Input Range			-2		2	V
DIGITAL INPUTS						
Input Voltage High	VIH		2.4			V
Input Voltage Low	VIL				0.8	V
Input Capacitance	CIN	(Note 1)			10	pF
Input Current	lin	$V_{IN} = 0 \text{ or } V_{CC}$	-1		1	μA
POWER SUPPLIES	I					
V <sub>DD</sub> Analog Power-Supply Range	V <sub>DD</sub>		7		14	V
Vss Analog Power-Supply Range	V <sub>SS</sub>		-9		-5	V
Digital Power Supply	Vcc		4.75	5	5.25	V
Positive Supply Current	IDD	R <sub>L</sub> = ∞		10	13	mA
Negative Supply Current	ISS	R <sub>L</sub> = ∞		9	12	mA
Digital Supply Current	100	(Note 3)			0.5	
Digital Supply Current	ICC	(Note 4)			5	mA
PSRR, $\Delta V_{OUT} / \Delta V_{DD}$		V <sub>DD</sub> = 14V ±5%		94		dB
PSRR, $\Delta V_{OUT} / \Delta V_{SS}$		$V_{SS} = -9V \pm 5\%$		98		dB

# INTERFACE TIMING CHARACTERISTICS

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND_{-}} = 0, V_{REF_{-}} = +4.500V, V_{REF_{-}} = -2.000V, Figure 2, T_A = T_{MIN}$  to T\_MAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
CS Pulse Width Low	t1		50			ns
WR Pulse Width Low	t2		50			ns
LD Pulse Width Low	t3		50			ns
$\overline{\text{CS}}$ Low to $\overline{\text{WR}}$ Low	t4		0			ns
$\overline{\text{CS}}$ High to $\overline{\text{WR}}$ High	t5		0			ns
Data Valid to WR Setup	t <sub>6</sub>		50			ns
Data Valid to WR Hold	t7		0			ns
Address Valid to WR Setup	t8		15			ns
Address Valid to WR Hold	t9		0			ns

# **DYNAMIC CHARACTERISTICS**

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND} = 0, V_{REF} = - + = +4.500V, V_{REF} = - - = -2.000V, R_L = 10k\Omega$ , CL = 50pF, TA = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at TA = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Output Settling Time		To $\pm 1/2$ LSB of full scale		22		μs
Output Slew Rate				1		V/µs
Digital Feedthrough		(Note 5)		3		nVs
Digital Crosstalk		(Note 6)		3		nVs
Digital-to-Analog Glitch Impulse				120		nVs
DAC-to-DAC Crosstalk				3		nVs
Channel-to-Channel Isolation				100		dB
Output Noise Spectral Density		At $f = 1$ kHz		120		nV/√Hz

Note 1: Guaranteed by design. Not production tested.

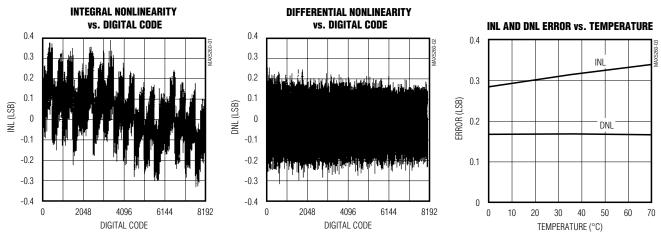
Note 2: Guaranteed by design when  $220\Omega$  resistor is in series with C<sub>L</sub> = 10,000pF.

**Note 3:** All digital inputs (D\_, A\_, WR, CS, LD, and CLR) at GND or V<sub>CC</sub> potential.

- **Note 4:** All digital inputs (D\_, A\_,  $\overline{WR}$ ,  $\overline{CS}$ ,  $\overline{LD}$ , and  $\overline{CLR}$ ) at +0.8V or +2.4V.
- **Note 5:** All data inputs (D0 to D12) transition from GND to  $V_{CC}$ , with  $\overline{WR} = V_{CC}$ .
- **Note 6:** All digital inputs (D\_, A\_,  $\overline{WR}$ ,  $\overline{CS}$ ,  $\overline{LD}$ , and  $\overline{CLR}$ ) at +0.8V or +2.4V.

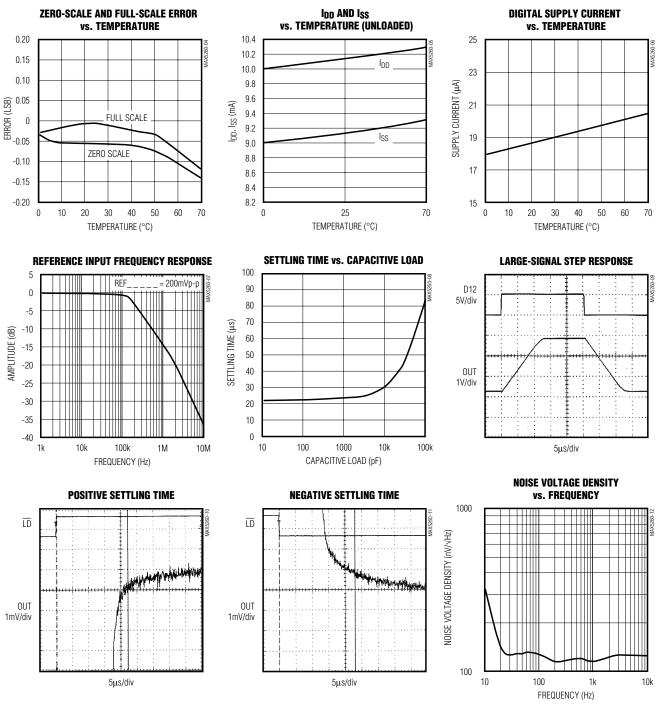
# **Typical Operating Characteristics**

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND_{-}} = 0, V_{REF_{-}+} = +4.500V, V_{REF_{-}-} = -2.000V, T_{A} = +25^{\circ}C$ , unless otherwise noted.)



### Typical Operating Characteristics (continued)

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND_{-}} = 0, V_{REF_{-}} + = +4.500V, V_{REF_{-}} - - = -2.000V, T_A = +25^{\circ}C, unless otherwise noted.)$ 



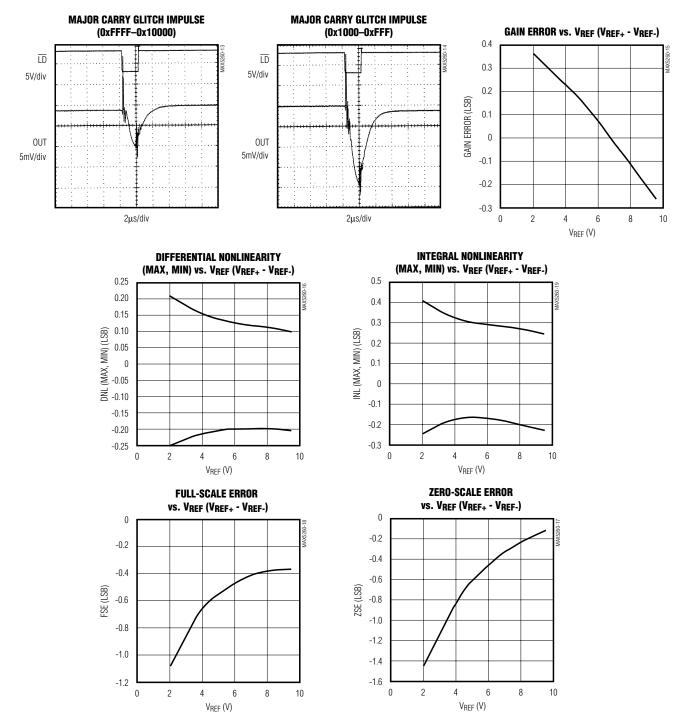
5

**MAX5839** 



### **Typical Operating Characteristics (continued)**

 $(V_{DD} = +14V, V_{SS} = -9V, V_{CC} = +5V, V_{GND} = V_{DUTGND_{-}} = 0, V_{REF_{-}} + = +4.500V, V_{REF_{-}} - - = -2.000V, T_A = +25^{\circ}C$ , unless otherwise noted.)



N/IXI/N

# **Pin Description**

PIN	NAME	FUNCTION
1	DUTGNDAB	Device Sense Ground Input for OUTA and OUTB. In normal operation, OUTA and OUTB are referenced to DUTGNDAB. When CLR is low, OUTA and OUTB are forced to the potential on DUTGNDAB.
2	OUTA	DAC A Buffered Output Voltage
3	REFAB-	Negative Reference Input for DACs A and B
4	REFAB+	Positive Reference Input for DACs A and B
5, 38	V <sub>DD</sub>	Positive Analog Power Supply. Normally set to +14V. Connect both pins to the supply voltage. See <i>Grounding and Bypassing</i> section for bypass requirements.
6, 29	Vss	Negative Analog Power Supply. Normally set to -9V. Connect both pins to the supply voltage. See <i>Grounding and Bypassing</i> section for bypass requirements.
7	ĪD	Load Input. Drive this asynchronous input low to transfer the contents of the input latches to their respective DAC latches. DAC latches are transparent when $\overline{\text{LD}}$ is low and latched when $\overline{\text{LD}}$ is high.
8	A2	Address Bit 2 (MSB)
9	A1	Address Bit 1
10	AO	Address Bit 0 (LSB)
11	CS	Chip Select. Active-low input.
12	WR	Write Input. Active-low strobe for conventional memory write sequence. Input data latches are transparent when $\overline{WR}$ and $\overline{CS}$ are both low. $\overline{WR}$ latches data into the DAC input latch selected by A2–A0 on the rising edge of $\overline{CS}$ .
13	Vcc	Digital Power Supply. Normally set to +5V. See <i>Grounding and Bypassing</i> section for bypass require- ments.
14	GND	Ground
15–27	D0-D12	Data Bits 0–12. Offset binary coding.
28	CLR	Clear Input. Drive CLR low to force all DAC outputs to the voltage on their respective DUTGND Does not affect the status of internal registers. All DACs return to their previous levels when CLR goes high.
30	REFGH+	Positive Reference Input for DACs G and H
31	REFGH-	Negative Reference Input for DACs G and H

\_\_\_\_\_Pin Description (continued)

PIN	NAME	FUNCTION
32	OUTH	DAC H Buffered Output Voltage
33	DUTGNDGH	Device Sense Ground Input for OUTG and OUTH. In normal operation, OUTG and OUTH are referenced to DUTGNDGH. When CLR is low, OUTG and OUTH are forced to the potential on DUTGNDGH.
34	OUTG	DAC G Buffered Output Voltage
35	OUTF	DAC F Buffered Output Voltage
36	DUTGNDEF	Device Sense Ground Input for OUTE and OUTF. In normal operation, OUTE and OUTF are referenced to DUTGNDEF. When CLR is low, OUTE and OUTF are forced to the potential on DUTGNDEF.
37	OUTE	DAC E Buffered Output Voltage
39	REFCDEF+	Positive Reference Input for DACs C, D, E, and F
40	REFCDEF-	Negative Reference Input for DACs C, D, E, and F
41	OUTD	DAC D Buffered Output Voltage
42	DUTGNDCD	Device Sense Ground Input for OUTC and OUTD. In normal operation, OUTC and OUTD are referenced to DUTGNDCD. When CLR is low, OUTC and OUTD are forced to the potential on DUTGNDCD.
43	OUTC	DAC C Buffered Output Voltage
44	OUTB	DAC B Buffered Output Voltage

MAX5839

M/XI/M

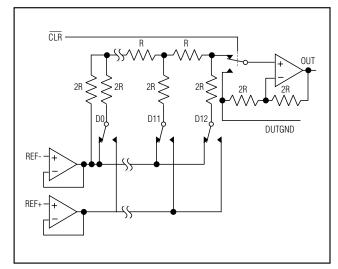


Figure 1. DAC Simplified Circuit

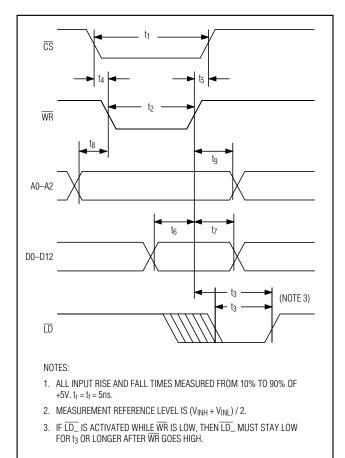


Figure 2. Digital Timing Diagram



### **Detailed Description**

#### **Analog Section**

The MAX5839 contains eight 13-bit voltage-output DACs. These DACs are "inverted" R-2R ladder networks that convert 13-bit digital inputs into equivalent analog output voltages, in proportion to the applied reference voltages (Figure 1). The MAX5839 has three positive reference inputs (REF\_\_\_\_+) and three negative reference inputs (REF\_\_\_\_-). The difference from REF\_\_\_\_+ to REF\_\_\_\_-, multiplied by two, sets the DAC output span.

In addition to the differential reference inputs, the MAX5839 has four analog-ground input pins (DUT-GND\_ \_). When CLR is high (unasserted), the voltage on DUTGND\_ \_ offsets the DAC output voltage range. If CLR is asserted, the output amplifier is forced to the voltage present on DUTGND\_ \_.

### **Reference and DUTGND Inputs**

All of the MAX5839's reference inputs are buffered with precision amplifiers. This allows the flexibility of using resistive dividers to set the reference voltages. Because of the relatively high multiplying bandwidth of the reference input (188kHz), any signal present on the reference pin within this bandwidth is replicated on the DAC output.

The DUTGND pins of the MAX5839 are connected to the negative source resistor (nominally  $84k\Omega$ ) of the output amplifier. The DUTGND pins are typically connected directly to analog ground. Each of these pins has an input current that varies with the DAC digital code. If the DUTGND pins are driven by external circuitry, budget  $\pm 200\mu A$  per DAC for load current.

#### **Output Buffer Amplifiers**

The MAX5839's voltage outputs are internally buffered by precision gain-of-two amplifiers with a typical slew rate of 1V/µs. With a full-scale transition at its output, the typical settling time to  $\pm 1/2$ LSB is 22µs. This settling time does not significantly vary with capacitive loads less than 10,000pF.

#### **Output Deglitching Circuit**

The MAX5839's internal connection from the DAC ladder to the output amplifier contains special deglitch circuitry. This glitch/deglitch circuitry is enabled on the falling edge of  $\overline{\text{LD}}$  to remove the glitch from the R-2R DAC. This enables the MAX5839 to exhibit a fraction of the glitch impulse energy of parts without the deglitching circuit.

#### **Digital Inputs and Interface Logic**

All digital inputs are compatible with both TTL and CMOS logic. The MAX5839 interfaces with microprocessors using a data bus at least 13 bits wide. The interface is double buffered, allowing simultaneous updating of all DACs. There are two latches for each DAC (see Functional Diagram): an input latch that receives data from the data bus, and a DAC latch that receives data from the input latch. Address lines A0, A1, and A2 select which DAC's input latch receives data from the data bus, as shown in Table 1. Both the input latches and the DAC latches are transparent when CS, WR, and LD are all low. Any change of D0-D12 during this condition appears at the output instantly. Transfer data from the input latches to the DAC latches by asserting the asynchronous LD signal. Each DAC's analog output reflects the data held in its DAC latch. All control inputs are level triggered. Table 2 is an interface truth table.

### Table 1. MAX5839 DAC Addressing

A2	A1	A0	FUNCTION
0	0	0	DAC A input latch
0	0	1	DAC B input latch
0	1	0	DAC C input latch
0	1	1	DAC D input latch
1	0	0	DAC E input latch
1	0	1	DAC F input latch
1	1	0	DAC G input latch
1	1	1	DAC H input latch

### Table 2. Interface Truth Table

CLR	LD	WR	CS	FUNCTION
Х	Х	0	0	Input register transparent
Х	Х	Х	1	Input register latched
Х	Х	1	Х	Input register latched
Х	0	Х	Х	DAC register transparent
Х	1	Х	Х	DAC register latched
0	Х	Х	Х	Outputs of DACs at DUTGND
1	1	Х	Х	Outputs of DACs set to volt- age defined by the DAC register, the references, and the corresponding DUTGND

X = Don't care

#### Input Write Cycle

Data can be latched or transferred directly to the DAC.  $\overline{CS}$  and  $\overline{WR}$  control the input latch, and  $\overline{LD}$  transfers information from the input latch to the DAC latch. The input latch is transparent when  $\overline{CS}$  and  $\overline{WR}$  are low, and the DAC latch is transparent when  $\overline{LD}$  is low. The address lines (A0, A1, A2) must be valid for the duration that  $\overline{CS}$  and  $\overline{WR}$  are low (Figure 1), to prevent data from being inadvertently written to the wrong DAC. Data is latched within the input latch when either  $\overline{CS}$  or  $\overline{WR}$  is high.

#### Loading the DACs

Taking  $\overline{\text{LD}}$  high latches data into the DAC latches. If  $\overline{\text{LD}}$  is brought low when  $\overline{\text{WR}}$  and  $\overline{\text{CS}}$  are low, the DAC addressed by A0, A1, and A2 is directly controlled by the data on D0–D12. This allows the maximum digital update rate; however, it is sensitive to any glitches or skew in the input data stream.

#### Asynchronous Clear

The MAX5839 has an asynchronous clear pin  $(\overline{\text{CLR}})$  that, when asserted, sets all DAC outputs to the voltage present on their respective DUTGND pins. Deassert CLR to return the DAC output to its previous voltage. Note that  $\overline{\text{CLR}}$  does not clear any of the internal digital registers.

### Applications Information

#### **Multiplying Operation**

The MAX5839 can be used for multiplying applications. Its reference accepts both DC and AC signals. Since the reference inputs are unipolar, multiplying operation is limited to two quadrants. See the graphs in the *Typical Operating Characteristics* for dynamic performance of the DACs and output buffers.

#### Digital Code and Analog Output Voltage

The MAX5839 uses offset binary coding. A 13-bit two's complement code is converted to a 13-bit offset binary code by adding  $2^{12} = 4096$ .

#### **Output Voltage Range**

For typical operation, connect DUTGND to signal ground, V<sub>REF+</sub> to +4.5V, and V<sub>REF-</sub> to -2.0V. Table 3 shows the relationship between digital code and output voltage.

The DAC digital code controls each leg of the 13-bit R-2R ladder. A code of 0x0 connects all legs of the ladder to REF-, corresponding to a DAC output voltage (VDAC) equal to REF-. A code of 0x1FFF connects all legs of the ladder to REF+, corresponding to a VDAC approximately equal to REF+.



### Table 3. Analog Voltage vs. Digital Code

INPUT CODE	OUTPUT VOLTAGE (V)
1 1111 1111 1111	+8.998413
1 0000 0000 0000	+4.500
0 1001 1101 1001	+600µ
0 0000 0000 0001	-3.998586
0 0000 0000 0000	-4.000

**Note:** Output voltage is based on REF + = +4.5V, REF - = -2.0V, and DUTGND = 0.

The output amplifier multiplies V<sub>DAC</sub> by 2, yielding an output voltage range of  $2 \cdot \text{REF-}$  to  $2 \cdot \text{REF+}$  (Figure 1). Further manipulation of the output voltage span is accomplished by offsetting DUTGND. The output voltage of the MAX5839 is described by the following equation:

$$V_{OUT} = 2 \left[ \left( V_{REF+} - V_{REF-} \right) \frac{DATA}{2^{13}} + V_{REF-} \right] - V_{OUTGND}$$

where DATA is the numeric value of the DAC's binary input code, and DATA ranges from 0 ( $2^0$ ) to 8191 ( $2^{13}$  - 1). The resolution of the MAX5839, defined as 1LSB, is described by the following equation:

$$LSB = \frac{2\left(REF+ - REF-\right)}{2^{13}}$$

#### **Reference Selection**

Because the MAX5839 has precision buffers on its reference inputs, the requirements for interfacing to these inputs are minimal. Select a low-drift, low-noise reference within the recommended REF+ and REF- voltage ranges. The MAX5839 does not require bypass capacitors on its reference inputs. Add capacitors only if the reference voltage source requires them to meet system specifications.

#### **Minimizing Output Glitch**

The MAX5839's internal deglitch circuitry is enabled on the falling edge of  $\overline{\text{LD}}$ . Therefore, to achieve optimum performance, drive  $\overline{\text{LD}}$  low after the inputs are either latched or steady state. This is best accomplished by having the falling edge of  $\overline{\text{LD}}$  occur at least 50ns after the rising edge of  $\overline{\text{CS}}$ .

#### Power Supplies, Grounding, and Bypassing

For optimum performance, use a multilayer PC board with an unbroken analog ground. For normal operation, connect the four DUTGND pins directly to the ground plane. Avoid sharing the connections of these sensitive pins with other ground traces.

As with any sensitive data acquisition system, connect the digital and analog ground planes together at a single point, preferably directly underneath the MAX5839. Avoid routing digital signals underneath the MAX5839 to minimize their coupling into the IC.

For normal operation, bypass V<sub>DD</sub> and V<sub>SS</sub> with  $0.1\mu$ F ceramic chip capacitors to the analog ground plane. To enhance transient response and capacitive drive capability, add 10 $\mu$ F tantalum capacitors in parallel with the ceramic capacitors. Note, however, that the MAX5839 does not require the additional capacitance for stability. Bypass V<sub>CC</sub> with a  $0.1\mu$ F ceramic chip capacitor to the digital ground plane.

#### **Power-Supply Sequencing**

To guarantee proper operation of the MAX5839, ensure that power is applied to V<sub>DD</sub> before V<sub>SS</sub> and V<sub>CC</sub>. Also ensure that V<sub>SS</sub> is never more than 300mV above ground. To prevent this situation, connect a Schottky diode between V<sub>SS</sub> and the analog ground plane, as shown in Figure 3. Do not power up the logic input pins before establishing the supply voltages. If this is not possible and the digital lines can drive more than 10mA, place current-limiting resistors (e.g., 470 $\Omega$ ) in series with the logic pins.

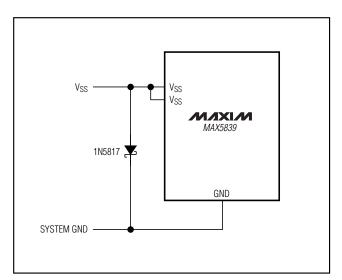


Figure 3. Schottky Diode Between VSS and GND

M/IXI/M

### **Driving Capacitive Loads**

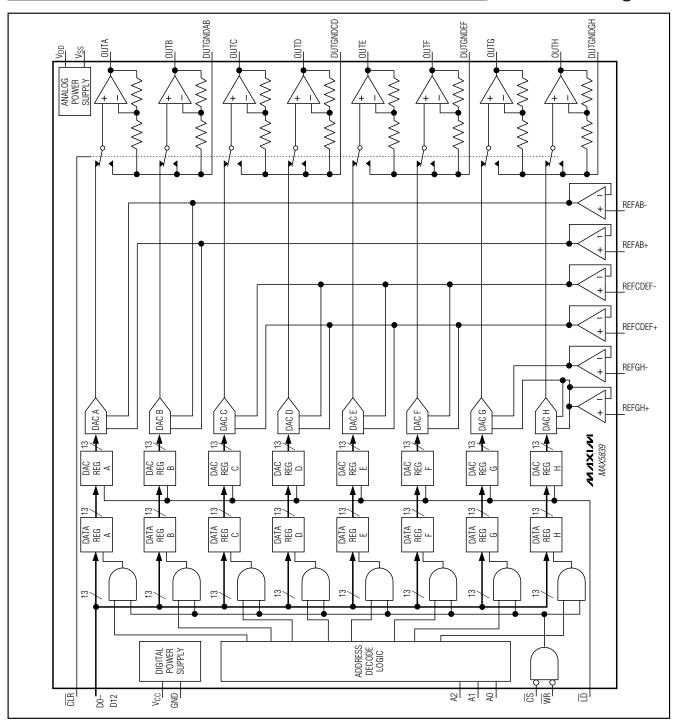
**Chip Information** 

The MAX5839 typically drives capacitive loads up to  $0.01\mu$ F without a series output resistor. However, whenever driving high capacitive loads, it is prudent to use a  $220\Omega$  series resistor between the MAX5839 output and the capacitive load.

TRANSISTOR COUNT: 10,973

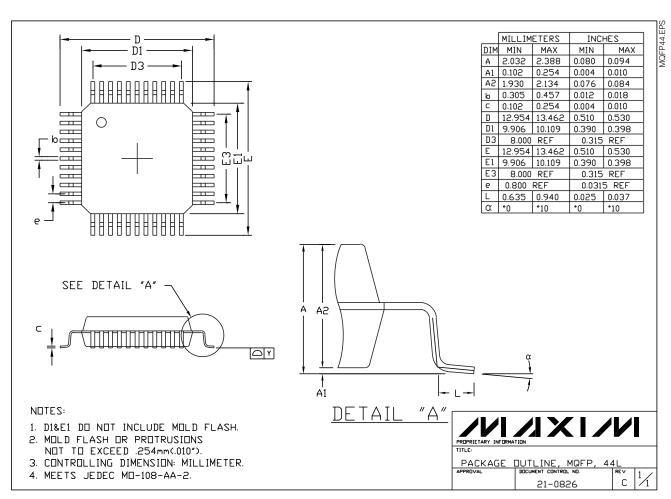
### \_Functional Diagram

**MAX5839** 



13





M/IXI/M

**MAX5839** 

NOTES

NOTES

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.



\_\_\_\_Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

© 1999 Maxim Integrated Products

Printed USA

is a registered trademark of Maxim Integrated Products.